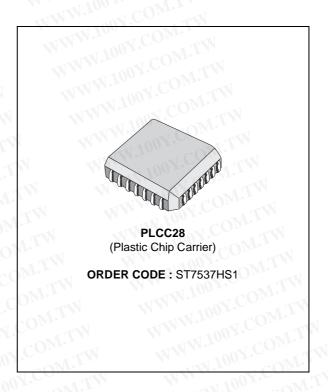
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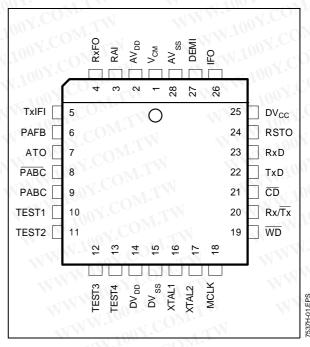
ST7537HS1

HOME AUTOMATION MODEM

- HALF DUPLEX ASYNCHRONOUS 2400bps FSK MODEM
- Tx CARRIER FREQUENCY SYNTHESIZED FROM EXTERNAL CRYSTAL
- LOW DISTORTION Tx SIGNAL
- Rx SENSITIVITY BETTER THAN 1mV_{RMS}
- CARRIER DETECTION
- WATCH-DOG INPUT
- RESET AND MASTER CLOCK OUTPUTS FOR MICROCONTROLLER
- POWER AMPLIFIER BIAS CURRENT CON-TROL (HIGH IMPEDANCE IN Rx MODE)
- SIMPLE AND ECONOMICAL APPLICATION SCHEMATICS
- COMPATIBLE WITH CENELEC EN 50065-1 AND FCC SPECIFICATION
- CARRIER DETECT CLAMPING ON RxD PROGRAMMABLE (ALLOWING DEMODULA-TION ON VERY LOW RECEIVE LEVEL, 1mV_{RMS} TYPICALLY)



PIN CONNECTIONS



DESCRIPTION

The ST7537HS1 is a half duplex asynchronous FSK MODEM designed for home automation communication on the domestic electric mains which complies with the EN 50065-1 CENELEC standard

It mainly operates from a 10V power supply and a 5V power supply for the microcontroller digital interface.

It is interfaced to the power line by an external driver, and a transformer (see Application Schematic Diagram). Its data transmission rate is 2400 bps and its carrier frequency is 132.45kHz.

June 1995

Pin Name	Pin Number	Pin Type	Description
V_{CM}	1	Analog	Common Mode Voltage
AV_{DD}	2	Supply	Analog Power Supply: 10V ±5 %
RAI	3 🕥	Analog	Receive Analog Input
RxFO	4	Analog	Receive Filter Output
TxIFI	5	Analog	Transmit and Intermediate Frequency Filters Test Input (mode TEST3)
PAFB	6	Analog	Power Amplifier Feed-back Input
ATO	N 7	Analog	Analog Transmit Output
PABC	8	Digital (10V)	Power Amplifier Bias Current Control Complementary Output
PABC	9	Digital (10V)	Power Amplifier Bias Current Control Output
TEST1	10	Digital	Tx to Rx Automatic Mode Switching Control Input
TEST2	11	Digital	Automatic Mode Switching Time and Watch-dog Time Reduction Control Input
TEST3	12	Digital	TxIFI Selection Input
TEST4	13	Digital	Undelayed Reset Input
DV_DD	14	Supply	Digital Power Supply : 10V ±5%
DV _{SS}	15	Supply	Digital Ground : 0V
XTAL1	16	Digital (10V)	Crystal Oscillator Input
XTAL2	17	Digital (10V)	Crystal Oscillator Output
MCLK	18	Digital	Master Clock Output
WD	19	Digital	Watch-dog Input
Rx/Tx	20	Digital	Rx or Tx Mode Selection Input
CD	21	Digital	Carrier Detect Output
TxD	22	Digital	Transmit Data Input
RxD	23	Digital	Receive Data Output
RSTO	24	Digital	Reset Output
DVcc	25	Supply	Digital Buffers Supply Voltage : 5V ±5 %
IFO	26	Analog	Intermediate Frequency Filter Output
DEMI	27	Analog	Demodulator Input
AVSS	28	Supply	Analog Ground: 0V

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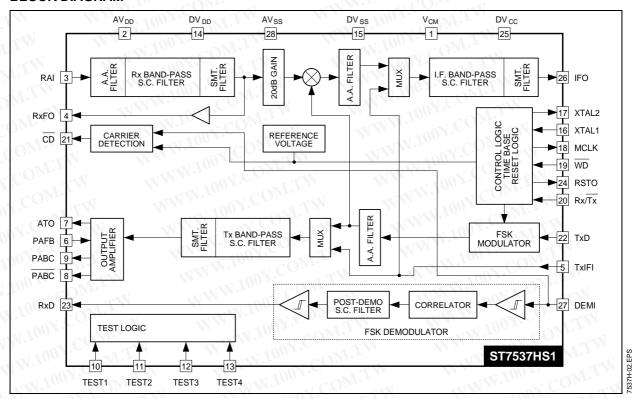
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BLOCK DIAGRAM



TRANSMIT SECTION

The transmit mode is set when $Rx/\overline{Tx} = 0$, if Rx/\overline{Tx} is held at 0 longer than 1 second, then the device switches automatically in the Rx mode. A new activation of the Tx mode requires Rx/\overline{Tx} to be returned to 1 for a minimum 2 microsecond period before being set to 0.

The Transmit Data (TxD) enter asynchronously the FSK modulator with a nominal intra-message data rate of 2400 bps.

The basic transmit frequencies are:

- f(TxD=0) = 133.05kHz
- f(TxD=1) = 131.85kHz

These frequencies are synthesized from a 11.0592MHz crystal oscillator; their precision is the same as the crystal one's (100ppm).

The modulated signal coming out of the FSK modulator is filtered by a switched-capacitor band-pass filter (Tx band-pass) in order to limit the output spectrum and to reduce the level of harmonic components.

The final stage of the Tx path consists of an operational amplifier which needs a feed-back signal (PAFB) from the power amplifier as shown on Application Schematic Diagram.

In Tx mode the Receive Data (RxD) signal is set to 1.

RECEIVE SECTION

The receive section is active when Rx/Tx = 1.

The Rx signal is applied on RAI and filtered by a band-pass switched capacitor filter (Rx band-pass) centered on the carrier frequency and whose bandwidth is around 12kHz.

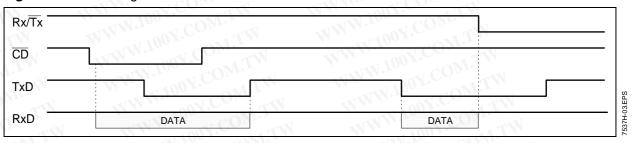
The Rx filter output is amplified by a 20dB gain stage which provides symetrical limitations for large voltage. The resulting signal is down-converted by a mixer which receives a local oscillator synthesized by the FSK modulator block. Finally an intermediate frequency band-pass filter (IF band-pass) whose central frequency is 5.4kHz improves the signal to noise ratio before entering the FSK demodulator.

The coupling of the intermediate frequency filter output (IFO) to the FSK demodulator input (DEMI) is made by an external capacitor C5 (100nF \pm 10%, 10V) which cancels the Rx path offset voltage.

The RxD output delivers the demodulated signal if the carrier detect (CD) signal is low and is set to high level when CD = 1.

The RxD output can delivers the demod<u>ulated</u> signal whatever the level of \overline{CD} (0 or 1) if Rx/Tx = 1 and TxD = 0 (see Figure 1).

Figure 1: Data Timing Chart



ADDITIONAL DIGITAL AND ANALOG FUNC-TIONS

Time base

A time base section delivers all the internal clocks from a crystal oscillator (11.0592MHz). The crystal is connected between XTAL1 and XTAL2 pins and needs two external capacitors C3 and C4 (22pF \pm 10%, 10V) for proper operation.

Reset and watch-dog

The reset output (RSTO) is driven high when the supply voltage is lower than Vrh (typically 7.6V) with an hysteresis Vrh-Vrl (typically 300mV) or when no negative transition occurs on the watch-dog input (WD) for more than 1.5 second (see the timing chart on Figure 2). When a reset occurs RSTO is held high for at least 50ms.

Signal detection

The Carrier Detect output (CD) is driven low when the input signal amplitude on RAI is greater than V_{CD} for at least T_{CD} (typically 6ms see the timing chart on Figure 3). When the input signal desappears or becomes lower than V_{CD}, CD is held low for at least Tcd before returning to a high level. V_{CD} is the carrier detection threshold voltage which is set internally to detect 5mV_{RMS} typically.

External power amplifier bias control

Two dedicated digital output (PABC and PABC) delivering a signal between 0V and 10V are driven

low respectively high, when the circuit is set in the receive mode (Rx/Tx=1) or when the transmit mode time out (1 second) is exceeded; in the same time the output ATO is put in a high impedance state.

TESTING FEATURES

- An additionnal amplifier allows the observation of the Rx band-pass filter output on pin RxFO.
- A direct input to the Tx band-pass filter and to the IF filter (TxIFI) is selected when TEST3 = 1.
- The 1 second normal duration of the Tx to Rx mode automatic switching is reduced to 488μs and the 1.5 second watch-dog time out is reduced to 46.3μs when TEST2 = 1.
- When TEST1 = 1 the Tx to Rx mode automatic switching is desactivated and the functional mode of the circuit is fully controlled by Rx/Tx.
- TEST4 is a reset input which allows an undelayed control of RSTO and of the internal state of the circuit.

POWER SUPPLIES WIRING PRECAUTIONS

The ST7537HS1 has two positive power supply terminals (AV_{DD} , DV_{DD}) and two ground terminals (AV_{SS} , DV_{SS}) in order to separate internal analog and digital supplies. The analog and digital terminals of each supply pair must be connected together externally for proper operation.

The V_{DD} must be protected against short-circuit for proper operation.

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ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
AV _{DD} /DV _{DD}	Supply Voltage (1)	- 0.3, + 12	V
Vı	Digital Input Voltage	DV _{SS} - 0.3, DV _{DD} + 0.3	V
Vo	Digital Output Voltage (microcontroller interface)	DV _{SS} - 0.3, DV _{CC} + 0.3	V
Vo	Digital Output Voltage (PABC and PABC)	DV _{SS} - 0.3, DV _{DD} + 0.3	V
lo	Digital Output Current	- 5, + 5	mA
V_{I}	Analog Input Voltage	AV_{SS} - 0.3, AV_{DD} + 0.3	V
Vo	Analog Output Voltage	AV_{SS} - 0.3, AV_{DD} + 0.3	V
lo	Analog Output Current	- 5, + 5	mA
P _D	Power Dissipation	500	mW
T _{oper}	Operating Temperature	0, + 70	°C
T _{stg}	Storage Temperature	- 55, + 150	°C

Notes:

The voltages are referenced to AV_{SS} and DV_{SS}.

Absolute maximum ratings are values beyond which damage to device may occur. Functional operation under these conditions is not implied.

GENERAL ELECTRICAL CHARACTERISTICS

 $(A/DV_{DD} = 10V, A/DV_{SS} = 0V, DV_{CC} = 5V \text{ and } 0^{\circ}C \le T_{amb} \le 70^{\circ}C, \text{ unless otherwise specificied})$

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
AV _{DD} DV _{DD}	Supply Voltage	W.100X.COM.TW	9.5	10	10.5	V
Al _{DD} + Dl _{DD}	Supply Current	MAN-TOOX CONT. TAN M	INW.	30	CO_{M}	mA
DV _{CC}	Digital Output Supply Voltage	M.M. TOON. COM.	4.75	. 001	5.25	V
DI _{CC}	Digital Output Supply Current	M.IOO COM.	TIN	1.5	<1 CC	mA
V _{IH}	High Level Input Voltage	Digital Inputs	4.2	W.10	01.	V
VIL	Low Level Input Voltage	Digital Inputs	4/1/	×11	0.8	V
V _{OH}	High Level Output Voltage	I _{OH} = -100μA ● Digital Outputs ● Digital Outputs PABC and PABC	4.9 9.8	MM	100X	V
V _{OL}	Low Level Output Voltage	I _{OL} = 100μA • Digital Outputs • Digital Outputs PABC and PABC		NWV	0.1 0.2	V
DC \	Duty Cycle	MCLK Output, C _L = 15pF	40	M.	60	%

TRANSMITTER ELECTRICAL CHARACTERISTICS

 $(A/DV_{DD} = 10V, A/DV_{SS} = 0V, DV_{CC} = 5V \text{ and } 0^{\circ}C \le T_{amb} \le 70^{\circ}C, \text{ unless otherwise specificied})$

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
VTAC	Max Carrier Output AC Voltage	$R_1 = 5.6k\Omega$	0.8	1.0	1.3	V_{RMS}
HD2	Second Harmonic Distortion	$R_L(AV_{SS}) = 5.6k\Omega$	IM	- 50	MA	dB
HD3	Third Harmonic Distortion	$R(ATO, PAFB) = 1k\Omega$	W	- 60		dB
FD	FSK Peak-to-peak Deviation	WW. TOO TO	1.	1200	41	Hz

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RECEIVER ELECTRICAL CHARACTERISTICS

(A/DV_{DD} = 10V, A/DV_{SS} = 0V, DV_{CC} = 5V and 0^{o} C \leq T_{amb} \leq 70^{o} C, unless otherwise specificied)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
V _{IN}	Input Sensitivity	W. W. W. O.K.C.	T	1	10	mV_{RMS}
V _{IN}	Maximum Input Signal	ON THE TWY IN C.	OM.		2	V _{RMS}
R _{IN}	Input Impedance	ON.TV W.100	15	1		kΩ
GRx	Receive Gain	f = 132.45kHz		20		dB
BER	Bit Error Rate (1)	$S/N = 15dB$, $S = 10mV_{RMS}$, N : white	Cor	10 ⁻⁵	10 ⁻³	
t _{DEM}	Demodulation Time	Alternate 0 , 1 sequence	4 CO	3	N	T bit
V _{CD}	Carrier Detection Level	f = 132.45kHz, sine wave		5	10	mV_{RMS}

Note 1: This parameter is guaranteed by correlation

ADDITIONAL DIGITAL AND ANALOG FUNCTIONS ELECTRICAL CHARACTERISTICS

(A/DV_{DD} = 10V, A/DV_{SS} = 0V, DV_{CC} = 5V and 0° C \leq T_{amb} \leq 70°C, unless otherwise specificied)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
V _{RH}	High Level Reset Voltage	See Figure 2	100 x.	7.9	UIN	V
V _{RL}	Low Level Reset Voltage	See Figure 2	1005	7.6	TTV	V
t _{RST}	Reset Time	See Figure 2	50	V.CO	T.	ms
t _{WD}	Watch-dog Pulse Width	See Figure 2	500	*7 C!	DMr.	ns
t _{WM}	Watch-dog Pulse Period	See Figure 2	800	01.	Mo	μs
tout	Watch-dog Time Out	See Figure 2	×11	001.	1.5	S
tcD	Carrier Detection Time	See Figure 3	3	· ooV	6.5	ms

Figure 2: Reset and Watch-dog Timing Chart

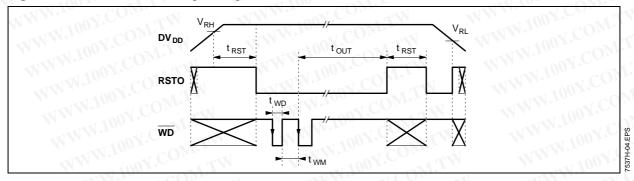
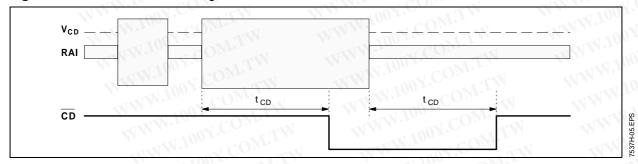


Figure 3: Carrier Detection Timing Chart



7537H-07.TBL

FILTER TEMPLATES

Receive and Transmit Filter

Frequency	1007	Gain (dB)	LM
Frequency (kHz)	Min.	Тур.	Max.
92	41. Jan	-1 COM	- 30
126.45	- 5	- 3	- 2
Ref 132.45	1 11 11.	0	WT
138.45	- 5	-3	- 2
180	W. Tank	100 1.	- 30

Intermediate FrequencyFilter

Frequency	Gain (dB)					
Frequency (kHz)	Min.	Тур.	Max			
2.4	OM		- 35			
4.3	- 4	- 3	- 1			
Ref 5.4	TILL	0				
6.5	C - 5	- 3	- 2			
11.6	· Mon	J- 1	- 35			

APPLICATION SCHEMATIC INFORMATIONS

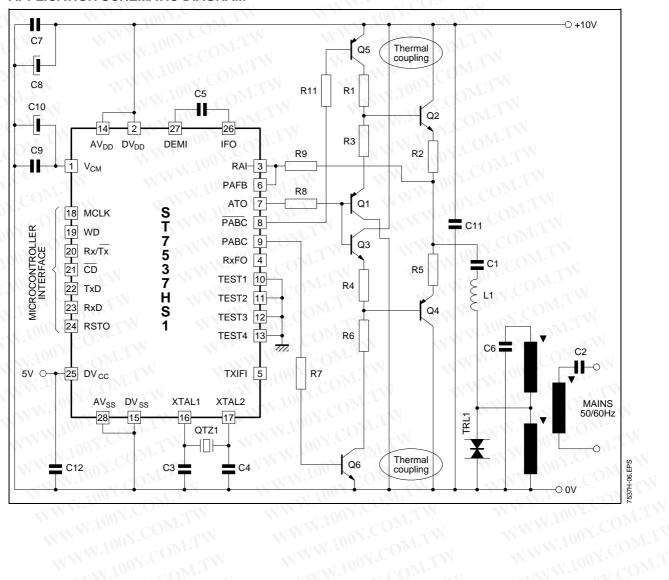
. 00	RESISTORS			1001.			CAPACITORS			
1.700	R1	180Ω		C1	1μF	TW	Ceramic 50			
N.10'	R2	2.2Ω		C2	470nF	- 1	Paper, class X2			
-x1 1	R3	2.2Ω		C3 (2)	22pF	10%	Ceramic 10V			
111.	R4	2.2Ω	1	C4 (2)	22pF	10%	Ceramic 10V			
WW.	R5	2.2Ω		C5	100nF	10%	Ceramic 10V			
· VIV	R6	180Ω	4 1	C6	6.8nF	5%	Plastic Film 50V			
NAA.	R7	47kΩ	7	C7	100nF	$\sim 0M.T$	Ceramic 10V			
WW	R8	1kΩ	W	C8	2.2μF		IM MAINTON ONITH			
· V	R9	1kΩ	5%	C9	100nF	COL	Ceramic 10V			
	R11	47kΩ	. 1	C10	2.2μF	of COM	MWW. TOWN. COMM.	V		
	- xx 10	INDUCTOR	RI.TV	C11 (1)	100nF		Ceramic 10V	. · ·		
	L1	10μΗ	≅ 1.5Ω	C12 (1)	100nF	01.00	Ceramic 10V	IN		
	T	TRANSISTORS			TRANSIL					
	TANK!	Q1:2N290		TRL1: SGS-THOMSON P6KE6V8CP						
	11 11	Q2 : 2N2222 Q3 : 2N2222			TRANSFORMER					
	MW	Q4:2N290	7	TR1 : TO	(O T1002 N	1,100%	ON:TW WW.100x.	7		
		Q5 : 2N2907 Q6 : 2N2222			WW	4005	CRYSTAL	537H-08.TB		
	-7				QTZ1 : 11.0592MHz parallel resonance					
	Notes: 1	. These capa . The value o	acitors might n of these capac	ight not be necessary if the overall power supplies decoupling is sufficient. capacitors depends on the crystal parameters.						

WWW.1007

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APPLICATION SCHEMATIC DIAGRAM



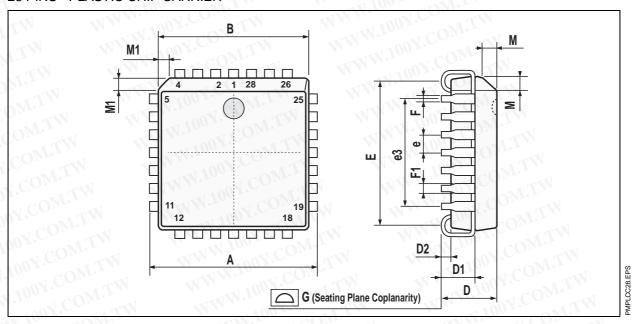
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PACKAGE MECHANICAL DATA

28 PINS - PLASTIC CHIP CARRIER



Dimensions	WILL	Millimeters	1001.001.	Inches				
	Min.	Тур.	Max.	Min.	Typ.	Max.		
A	12.32	VIV	12.57	0.485	TWW.IO	0.495		
В	11.43	M 4.	11.58	0.450	W. 100	0.456		
N D	4.2	WW	4.57	0.165	WW	0.180		
D1	2.29	-111	3.04	0.090	MW	0.120		
D2	0.51	7/1	1001.	0.020	W.J	ON CON		
WE	9.91	N N	10.92	0.390	WW	0.430		
е	CON	1.27	WW. L	COM	0.050	· any.Co		
e3	M_{II}	7.62	100	COM.	0.300	1.100		
F	OUX.CO	0.46	1007	TIME	0.018	100 Y.		
F1	COM	0.71	WWW.	V.COM TV	0.028	W. CONT.		
G	100 x CON		0.101	COM	- T	0.004		
М	1007.0	1.24	W 10	DY. OM.T	0.049	11 100 I		
M1	N. P. CO.	1.143	MAN	ON CONTRACT	0.045	100		

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